

Product Detail

Part Num: IXTV96N25T
Description: 2nd Generation Trench Gate Power MOSFETs
Configuration: Single
Package Style: PLUS220
Status: Active Part

Parameter	IXTV96N25T
VDSS, max, (V)	250
ID(cont), TC=25°C, (A)	96
RDS(on), max, TJ=25°C, (?)	0.029
Ciss, typ, (pF)	6100
Qg, typ, (nC)	114
trr, typ, (ns)	158
RthJC, max, (C/W)	0.20
PD, (W)	625